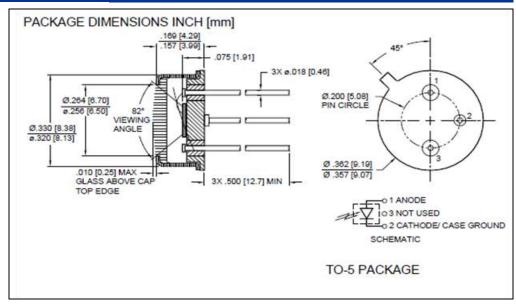


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Precision – Control – Results





DESCRIPTION

The SD197-121-041 is a high sensitivity, low capacitance and noise, 5mm diameter active area InGaAs photodiode, sensitive to wavelengths in visible extended (450-1700nm) spectral range and used for imaging and sensing applications. The photodetector is assembled in a TO-5 package.

FEATURES

- Low Noise
- Low Dark Current and Capacitance
- High Sensitivity
- Detection in LWIR

RELIABILITY

This API high-reliability detector is in principle able to meet military test requirements (Mil-STD-750, Mil-STD-883) after proper screening and group test.

Contact API for recommendations on specific test conditions and procedures.

APPLICATIONS

- Industrial Sensing
- · Security and Defense
- Communication
- Medical

ABSOLUTE MAXIMUM RATINGS

SYMBOL	MIN	MAX	UNITS
Operating Temperature	0	+85	°C
Storage Temperature	-25	+85	°C
Soldering Temperature	-	+240	°C
Wavelength Range	450	1700	nm
Reverse Voltage	-	20	V

T_a = 23°C non condensing see recommended reflow profile





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OPTO-ELECTRICAL P		T _a = 23°C unless noted otherwise					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS		
Breakdown Voltage	$I_{\text{bias}} = 100 \mu\text{A}$	10	-	-	V		
Responsivity	λ= 660 nm	-	0.35	-	A/W		
Responsivity	λ= 1200 nm	-	0.90	-	A/W		
Shunt Resistance	V _{bias} = 10 mV	-	30	-	MΩ		
Dark Current	$V_{\text{bias}} = 5V$	-	-	10	nA		
Capacitance	$V_{\text{bias}} = 0V$; $f = 1 \text{ MHz}$	-	-	100	pF		
Rise Time (50 Ω load)	$V_{bias} = 24V; \lambda = 826 \text{ nm}$	-	5	-	ns		
Noise Equivalent Power	λ= 900 nm	-	10	-	10 ⁻¹⁴ W/Hz ^{0.5}		

TYPICAL PERFORMANCE

SPECTRAL RESPONSE

